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Details

Product Status	Active
Core Processor	Coldfire V1
Core Size	32-Bit Single-Core
Speed	50MHz
Connectivity	CANbus, I ² C, SCI, SPI, USB OTG
Peripherals	LVD, PWM, WDT
Number of I/O	66
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 12x12b
Oscillator Type	External
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	80-LQFP
Supplier Device Package	80-LQFP (14x14)
Purchase URL	https://www.e-xfl.com/pro/item?MUrl=&PartUrl=mcf51jm64evlk

Table of Contents

1	MCF51JM128 Family Configurations	3
1.1	Device Comparison	3
1.2	Block Diagram	4
1.3	Features	5
1.4	Part Numbers	8
1.5	Pinouts and Packaging	10
2	Preliminary Electrical Characteristics	15
2.1	Parameter Classification	15
2.2	Absolute Maximum Ratings	15
2.3	Thermal Characteristics	16
2.4	Electrostatic Discharge (ESD) Protection Characteristics	17
2.5	DC Characteristics	18
2.6	Supply Current Characteristics	21
2.7	Analog Comparator (ACMP) Electricals	23
2.8	ADC Characteristics	23
2.9	External Oscillator (XOSC) Characteristics	26
2.10	MCG Specifications	27
2.11	AC Characteristics	28
2.12	SPI Characteristics	31
2.13	Flash Specifications	34
2.14	USB Electricals	34
2.15	EMC Performance	35
3	Mechanical Outline Drawings	36
3.1	80-pin LQFP	36
3.2	64-pin LQFP	39
3.3	64-pin QFP	42
3.4	44-pin LQFP	45
4	Revision History	48

List of Figures

Figure 1.	MCF51JM128 Block Diagram	4
Figure 2.	80-pin LQFP	10
Figure 3.	64-pin QFP and LQFP	11
Figure 4.	44-pin LQFP	12
Figure 5.	Typical Low-side Drive (sink) characteristics – High Drive (PTxDSn = 1)	20
Figure 6.	Typical Low-side Drive (sink) characteristics – Low Drive (PTxDSn = 0)	20
Figure 7.	Typical High-side Drive (source) characteristics – High Drive (PTxDSn = 1)	21
Figure 8.	Typical High-side Drive (source) characteristics – Low Drive (PTxDSn = 0)	21
Figure 9.	ADC Input Impedance Equivalency Diagram	24
Figure 10.	Reset Timing	29
Figure 11.	IRQ/KBIPx Timing	29
Figure 12.	Timer External Clock	29

Figure 13.	Timer Input Capture Pulse	30
Figure 14.	SPI Master Timing (CPHA = 0)	32
Figure 15.	SPI Master Timing (CPHA = 1)	32
Figure 16.	SPI Slave Timing (CPHA = 0)	33
Figure 17.	SPI Slave Timing (CPHA = 1)	33
Figure 18.	80-pin LQFP Diagram - I	36
Figure 19.	80-pin LQFP Diagram - II	37
Figure 20.	80-pin LQFP Diagram - III	38
Figure 21.	64-pin LQFP Diagram - I	39
Figure 22.	64-pin LQFP Diagram - II	40
Figure 23.	64-pin LQFP Diagram - III	41
Figure 24.	64-pin QFP Diagram - I	42
Figure 25.	64-pin QFP Diagram - II	43
Figure 26.	64-pin QFP Diagram - III	44
Figure 27.	44-pin LQFP Diagram - I	45
Figure 28.	44-pin LQFP Diagram - II	46
Figure 29.	44-pin LQFP Diagram - III	47

List of Tables

Table 1.	MCF51JM128 Series Device Comparison	3
Table 2.	MCF51JM128 Series Functional Units	5
Table 3.	Orderable Part Number Summary	8
Table 4.	Pin Assignments by Package and Pin Sharing Priority	12
Table 5.	Parameter Classifications	15
Table 6.	Absolute Maximum Ratings	16
Table 7.	Thermal Characteristics	16
Table 8.	ESD and Latch-up Test Conditions	17
Table 9.	ESD and Latch-Up Protection Characteristics	18
Table 10.	DC Characteristics	18
Table 11.	Supply Current Characteristics	21
Table 12.	Analog Comparator Electrical Specifications	23
Table 13.	5 Volt 12-bit ADC Operating Conditions	23
Table 14.	5 Volt 12-bit ADC Characteristics (VREFH = VDPA, VREFL = VSSA)	24
Table 15.	Oscillator Electrical Specifications (Temperature Range = –40 to 105°C Ambient)	26
Table 16.	MCG Frequency Specifications (Temperature Range = –40 to 125°C Ambient)	27
Table 17.	Control Timing	28
Table 18.	TPM Input Timing	29
Table 19.	MSCAN Wake-up Pulse Characteristics	30
Table 20.	SPI Timing	31
Table 21.	Flash Characteristics	34
Table 22.	Internal USB 3.3V Voltage Regulator Characteristics	35
Table 23.	Internal Revision History	50
Table 24.	Changes Between Revisions	51

1 MCF51JM128 Family Configurations

1.1 Device Comparison

The MCF51JM128 series consists of the devices compared in [Table 1](#).

Table 1. MCF51JM128 Series Device Comparison

Feature	MCF51JM128			MCF51JM64			MCF51JM32		
	80-pin	64-pin	44-pin	80-pin	64-pin	44-pin	80-pin	64-pin	44-pin
Flash memory size (KB)	128			64			32		
RAM size (KB)	16			16			16		
V1 ColdFire core with BDM (background debug module)	Yes								
ACMP (analog comparator)	Yes								
ADC channels (12-bit)	12		8	12		8	12		8
CAN (controller area network)	Yes	Yes	No	Yes	Yes	No	Yes	Yes	No
RNGA + CAU	Yes ¹								
CMT (carrier modulator timer)	Yes								
COP (computer operating properly)	Yes								
IIC1 (inter-integrated circuit)	Yes								
IIC2	Yes	No		Yes	No		Yes	No	
IRQ (interrupt request input)	Yes								
KBI (keyboard interrupts)	8	8	6	8	8	6	8	8	6
LVD (low-voltage detector)	Yes								
MCG (multipurpose clock generator)	Yes								
Port I/O ²	66	51	33	66	51	33	66	51	33
RGPIO (rapid general-purpose I/O)	16	6	0	16	6	0	16	6	0
RTC (real-time counter)	Yes								
SCI1 (serial communications interface)	Yes								
SCI2	Yes								
SPI1 (serial peripheral interface)	Yes								
SPI2	Yes								
TPM1 (timer/pulse-width modulator) channels	6	6	4	6	6	4	6	6	4
TPM2 channels	2								
USBOTG (USB On-The-Go dual-role controller)	Yes								
XOSC (crystal oscillator)	Yes								

¹ Only existed on special part number

1.3 Features

Table 2 describes the functional units of the MCF51JM128 series.

Table 2. MCF51JM128 Series Functional Units

Unit	Function
CF1CORE (V1 ColdFire core)	Executes programs and interrupt handlers
BDM (background debug module)	Provides a single-pin debugging interface (part of the V1 ColdFire core)
DBG (debug)	Provides debugging and emulation capabilities (part of the V1 ColdFire core)
SYSCTL (system control)	Provides LVD, COP, external interrupt request, and so on
FLASH (flash memory)	Provides storage for program code and constants
RAM (random-access memory)	Provides storage for program code, constants, and variables
RGPIO (rapid general-purpose input/output)	Allows I/O port access at CPU clock speeds
VREG (voltage regulator)	Controls power management throughout the device
USBOTG (USB On-The-Go)	Supports the USB On-The-Go dual-role controller
ADC (analog-to-digital converter)	Measures analog voltages at up to 12 bits of resolution
TPM1, TPM2 (timer/pulse-width modulators)	Provide a variety of timing-based features
CF1_INTIC (interrupt controller)	Controls and prioritizes all device interrupts
CAU (cryptographic acceleration unit)	Co-processor support for DES, 3DES, AES, MD5, and SHA-1
RNGA (random number generator accelerator)	32-bit random number generator that complies with FIPS-140
RTC (real-time counter)	Provides a constant-time base with optional interrupt
ACMP (analog comparator)	Compares two analog inputs
CMT (carrier modulator timer)	Infrared output used for the Remote Controller
IIC1, IIC2 (inter-integrated circuits)	Supports the standard IIC communications protocol
KBI (keyboard interrupt)	Provides pin interrupt capabilities
MCG (multipurpose clock generator)	Provides clocking options for the device, including a phase-locked loop (PLL) and frequency-locked loop (FLL) for multiplying slower reference clock sources
XOSC (crystal oscillator)	Supports low/high range crystals
CAN (controller area network)	Supports standard CAN communications protocol
SCI1, SCI2 (serial communications interfaces)	Serial communications UARTs that can support RS-232 and LIN protocols
SPI1, SPI2 (serial peripheral interfaces)	Provide a 4-pin synchronous serial interface

1.3.1 Feature List

- 32-bit Version 1 ColdFire Central Processor Unit (CPU)
 - Up to 50.33 MHz at 2.7 V – 5.5 V
 - Performance (Dhrystone 2.1):
 - 0.94 Dhrystone 2.1 MIPS per MHz when running from internal RAM
 - 0.76 Dhrystone 2.1 MIPS per MHz when running from flash
 - Implements Instruction Set Revision C (ISA_C)
 - Supports up to 30 peripheral interrupt requests and seven software interrupts
- On-chip memory
 - Up to 128 KB Flash memory with read/program/erase over full operating voltage and temperature range
 - Up to 16 KB static random access memory (RAM)
 - Security circuitry to prevent unauthorized access to RAM and flash contents
- Power-saving modes
 - Two low-power stop plus wait modes
 - Peripheral clock enable register can disable clocks to unused modules, thereby reducing currents; this behavior allows clocks to remain enabled to specific peripherals in Stop3 mode
 - Very lower power real-time counter for use in run, wait, and stop modes with internal and external clock sources
- Four Clock Source Options
 - Oscillator (XOSC) — Loop-control Pierce oscillator; crystal or ceramic resonator range of 31.25 kHz to 38.4 kHz or 1 MHz to 16 MHz
 - FLL/PLL controlled by internal or external reference
 - Trimmable internal reference allows 0.2% resolution and 2% deviation
- System protection features
 - Watchdog computer operating properly (COP) reset with option to run from dedicated 1 kHz internal clock source or bus clock
 - Low-voltage detection with reset or interrupt; selectable trip points
 - Illegal opcode and illegal address detection with programmable reset or exception response
 - Flash block protection
- Debug support
 - Single-wire Background debug interface
 - 4 Program Counters plus two address (optional data) breakpoint registers with programmable 1- or 2-level trigger response
 - 64-entry processor status and debug data trace buffer with programmable start/stop conditions
- Universal Serial Bus (USB) On-The-Go dual-role controller
 - Full-speed USB device controller
 - Fully compliant with USB specification 1.1 and 2.0
 - 16 bidirectional endpoints, with double buffering to provide the maximum throughput
 - Supports control, bulk, interrupt, and isochronous endpoints
 - Supports bus-powered capability with low-power consumption
 - Full-speed / low-speed host controller
 - Host mode allows control, bulk, interrupt, and isochronous transfers
 - OTG protocol logic
 - On-chip USB transceiver
 - On-chip 3.3 V USB regulator and pull-up resistors save system cost

- Controller area network (MSCAN)
 - Implementation of the CAN protocol — Version 2.0A/B
 - Five receive buffers with FIFO storage scheme
 - Three transmit buffers with internal prioritization using a “local priority” concept
 - Flexible maskable identifier filter programmable as 2x32-bit, 4x16-bit, or 8x8-bit
 - Programmable wakeup functionality with integrated low-pass filter
 - Programmable loopback mode supports self-test operation
 - Programmable bus-off recovery functionality
 - Internal timer for time-stamping of received and transmitted messages
- Cryptographic acceleration unit (CAU)
 - Co-processor support of DES, 3DES, AES, MD5, and SHA-1
- Random number generator accelerator (RNGA)
 - 32-bit random number generator that complies with FIPS-140
- Analog-to-digital converter (ADC)
 - 12-channel, 12-bit resolution
 - Output formatted in 12-, 10-, or 8-bit right-justified format
 - Single or continuous conversion, and selectable asynchronous hardware conversion trigger
 - Operation in Stop3 mode
 - Automatic compare function
 - Internal temperature sensor
- Analog comparators (ACMP)
 - Selectable interrupt on rising edge, falling edge, or either rising or falling edges of comparator output
 - Option to compare to fixed internal bandgap reference voltage
 - Option to route output to TPM module
 - Operation in Stop3 mode
- Inter-integrated circuit (IIC)
 - Up to 100 kbps with maximum bus loading
 - Multi-master operation
 - Programmable slave address
 - Supports broadcast mode and 10-bit address extension
- Serial communications interfaces (SCI)
 - Two SCIs with full-duplex, non-return-to-zero (NRZ) format
 - LIN master extended break generation
 - LIN slave extended break detection
 - Programmable 8-bit or 9-bit character length
 - Wake up on active edge
- Serial peripheral interfaces (SPI)
 - Two serial peripheral interfaces with full-duplex or single-wire bidirectional
 - Double-buffered transmit and receive
 - Programmable transmit bit rate, phase, polarity, and Slave Select output
 - MSB-first or LSB-first shifting
- Timer/pulse width modulator (TPM)
 - 16-bit free-running or modulo up/down count operation
 - Up to eight channels, where each channel can be an input capture, output compare, or edge-aligned PWM
 - One interrupt per channel plus terminal count interrupt

1.5 Pinouts and Packaging

Figure 2 shows the pinout of the 80-pin LQFP.

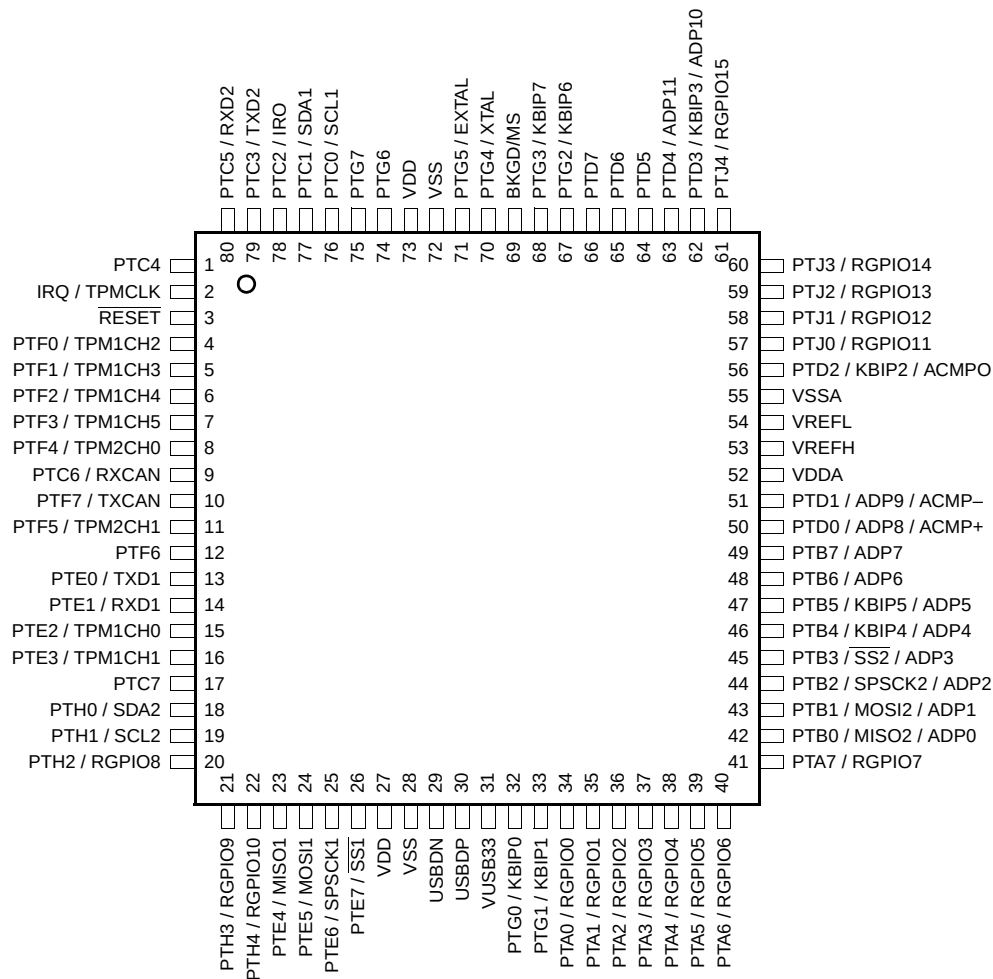


Figure 2. 80-pin LQFP

Figure 3 shows the pinout of the 64-pin LQFP and QFP.

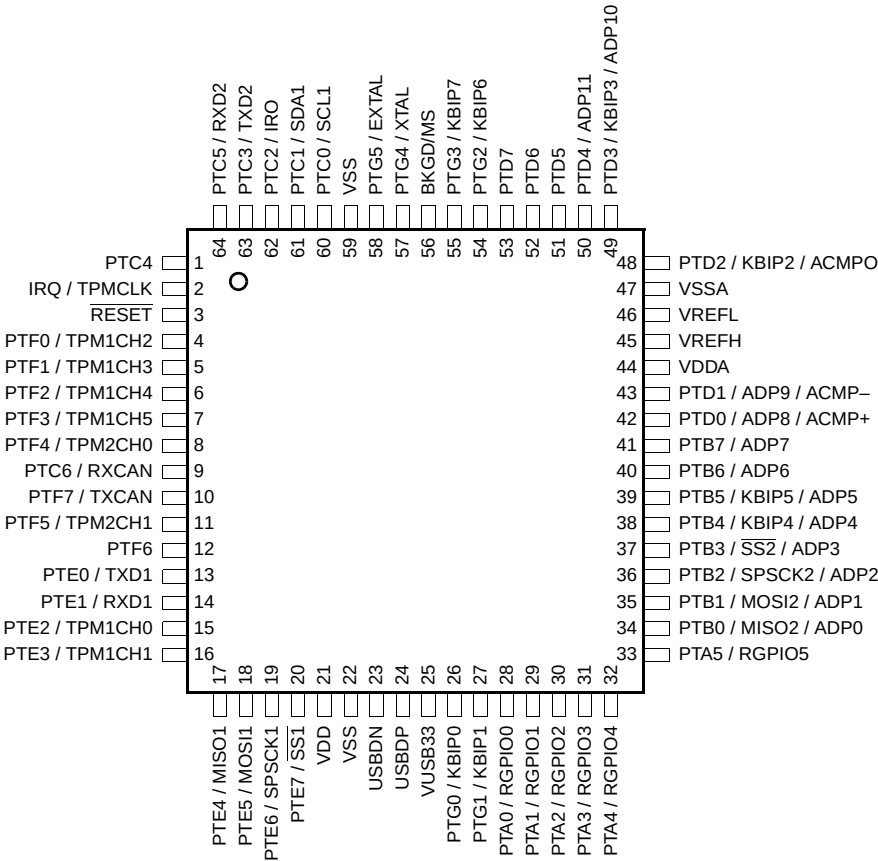


Figure 3. 64-pin QFP and LQFP

Preliminary Electrical Characteristics

- ¹ Typical values are based on characterization data at 25°C unless otherwise stated.
- ² Operating voltage with USB enabled can be found in [Section 2.14, "USB Electricals."](#)
- ³ Measured with $V_{In} = V_{DD}$ or V_{SS} .
- ⁴ Measured with $V_{In} = V_{SS}$.
- ⁵ Measured with $V_{In} = V_{DD}$.
- ⁶ This is the voltage below which the contents of RAM are not guaranteed to be maintained.

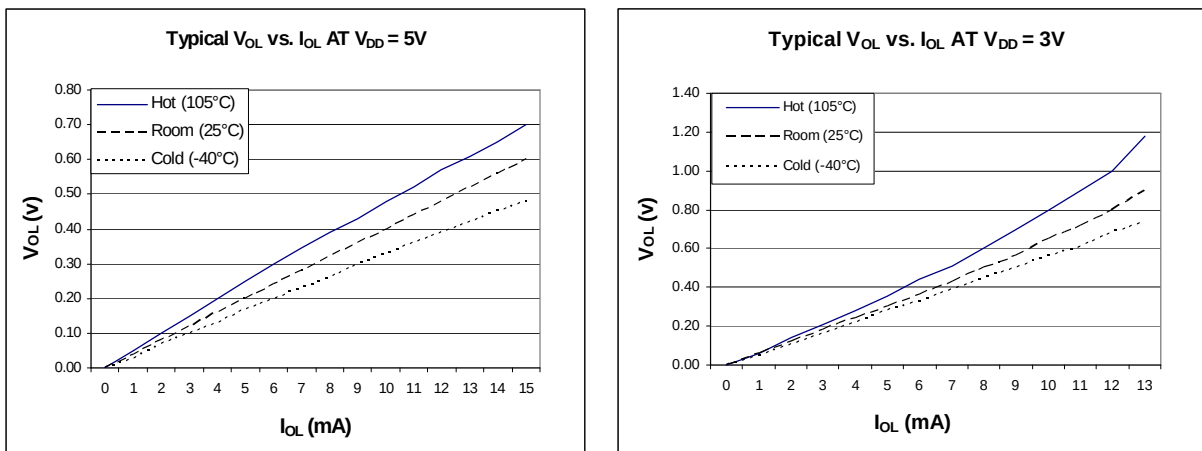


Figure 5. Typical Low-side Drive (sink) characteristics – High Drive (PTxDSn = 1)

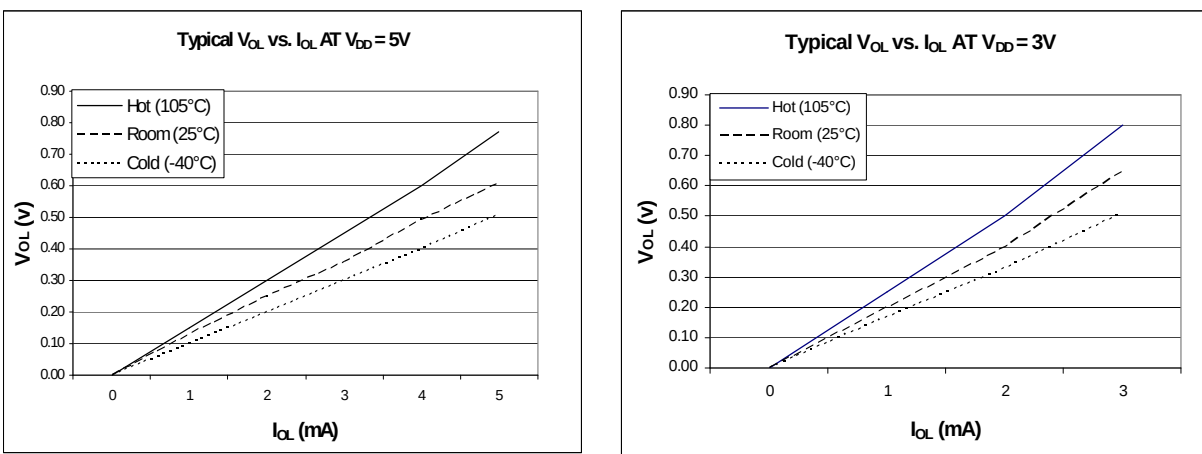


Figure 6. Typical Low-side Drive (sink) characteristics – Low Drive (PTxDSn = 0)

Table 14. 5 Volt 12-bit ADC Characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$) (continued)

Characteristic	Conditions	C	Symb	Min	Typ ¹	Max	Unit	Comment
Conversion Time (Including sample time)	Short Sample (ADLSMP=0)	T	t_{ADC}	—	20	—	ADCK cycles	See Table 9 for conversion time variances
	Long Sample (ADLSMP=1)			—	40	—		
Sample Time	Short Sample (ADLSMP=0)	T	t_{ADS}	—	3.5	—	ADCK cycles	
	Long Sample (ADLSMP=1)			—	23.5	—		
Total Unadjusted Error	12 bit mode	T	E_{TUE}	—	± 3.0	—	LSB ²	Includes quantization
	10 bit mode	P		—	± 1	± 2.5		
	8 bit mode	T		—	± 0.5	± 1.0		
Differential Non-Linearity	12 bit mode	T	DNL	—	± 1.75	—	LSB ²	
	10 bit mode ³	P		—	± 0.5	± 1.0		
	8 bit mode ³	T		—	± 0.3	± 0.5		
Integral Non-Linearity	12 bit mode	T	INL	—	± 1.5	—	LSB ²	
	10 bit mode	T		—	± 0.5	± 1.0		
	8 bit mode	T		—	± 0.3	± 0.5		
Zero-Scale Error	12 bit mode	T	E_{ZS}	—	± 1.5	—	LSB ²	$V_{ADIN} = V_{SSAD}$
	10 bit mode	P		—	± 0.5	± 1.5		
	8 bit mode	T		—	± 0.5	± 0.5		
Full-Scale Error	12 bit mode	T	E_{FS}	—	± 1	—	LSB ²	$V_{ADIN} = V_{DDAD}$
	10 bit mode	T		—	± 0.5	± 1		
	8 bit mode	T		—	± 0.5	± 0.5		
Quantization Error	12 bit mode	D	E_Q	—	-1 to 0	—	LSB ²	
	10 bit mode			—	—	± 0.5		
	8 bit mode			—	—	± 0.5		
Input Leakage Error	12 bit mode	D	E_{IL}	—	± 1	—	LSB ²	Pad leakage ⁴ * R_{AS}
	10 bit mode			—	± 0.2	± 2.5		
	8 bit mode			—	± 0.1	± 1		
Temp Sensor Voltage	25°C	D	V_{TEMP25}	—	1.396	—	V	
Temp Sensor Slope	-40°C - 25°C	D	m	—	3.266	—	mV/°C	
	25°C - 125°C			—	3.638	—		

¹ Typical values assume $V_{DDA} = 5.0V$, Temp = 25°C, $f_{ADCK} = 1.0MHz$ unless otherwise stated. Typical values are for reference only and are not tested in production.

² 1 LSB = $(V_{REFH} - V_{REFL})/2^N$

³ Monotonicity and No-Missing-Codes guaranteed in 10 bit and 8 bit modes

⁴ Based on input pad leakage current. Refer to pad electricals.

2.9 External Oscillator (XOSC) Characteristics

Table 15. Oscillator Electrical Specifications (Temperature Range = –40 to 105°C Ambient)

Num	C	Rating	Symbol	Min	Typ ¹	Max	Unit
1		Oscillator crystal or resonator (EREFS = 1, ERCLKEN = 1) - Low range (RANGE = 0) - High range (RANGE = 1) FEE or FBE mode ² - High range (RANGE = 1) PEE or PBE mode ³ - High range (RANGE = 1, HGO = 1) BLPE mode - High range (RANGE = 1, HGO = 0) BLPE mode	f_{lo} f_{hi-ll} f_{hi-pll} f_{hi-hgo} f_{hi-lp}	32 1 1 1 1	— — — — —	38.4 5 16 16 8	kHz MHz MHz MHz MHz
2		Load capacitors	C_1 C_2	See crystal or resonator manufacturer's recommendation.			
3		Feedback resistor - Low range (32 kHz to 38.4 kHz) - High range (1 MHz to 16 MHz)	R_F		10 1		MΩ MΩ
4	—	Series resistor - Low range, low gain (RANGE = 0, HGO = 0) - Low range, high gain (RANGE = 0, HGO = 1) - High range, low gain (RANGE = 1, HGO = 0) - High range, high gain (RANGE = 1, HGO = 1)	R_S	— — — — — — —	0 100 0 0 0 0 0	— — — 0 10 20	kΩ
5	T	Crystal start-up time ⁴ - Low range, low gain (RANGE = 0, HGO = 0) - Low range, high gain (RANGE = 0, HGO = 1) - High range, low gain (RANGE = 1, HGO = 0) ⁵ - High range, high gain (RANGE = 1, HGO = 1) ⁵	$t_{CSTL-LP}$ $t_{CSTL-HGO}$ $t_{CSTH-LP}$ $t_{CSTH-HGO}$	— — — —	200 400 5 15	— — — —	ms
6	T	Square wave input clock frequency (EREFS = 0, ERCLKEN = 1) - FEE or FBE mode ² - PEE or PBE mode ³ - BLPE mode	f_{extal}	0.03125 1 0	— — —	5 16 40	MHz MHz MHz

¹ Data in Typical column was characterized at 5.0 V, 25°C or is typical recommended value.

² When MCG is configured for FEE or FBE mode, input clock source must be divisible using RDIV to within the range of 31.25 kHz to 39.0625 kHz.

³ When MCG is configured for PEE or PBE mode, input clock source must be divisible using RDIV to within the range of 1 MHz to 2 MHz.

⁴ This parameter is characterized and not tested on each device. Proper PC board-layout procedures must be followed to achieve specifications.

⁵ 4 MHz crystal

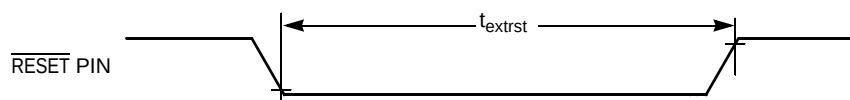


Figure 10. Reset Timing

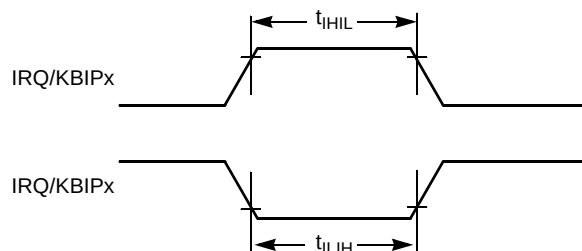


Figure 11. IRQ/KBIPx Timing

2.11.2 Timer/PWM (TPM) Module Timing

Synchronizer circuits determine the shortest input pulses that can be recognized or the fastest clock that can be used as the optional external source to the timer counter. These synchronizers operate from the current bus rate clock.

Table 18. TPM Input Timing

NUM	C	Function	Symbol	Min	Max	Unit
1	—	External clock frequency	f_{TPMext}	dc	$f_{\text{Bus}}/4$	MHz
2	—	External clock period	t_{TPMext}	4	—	t_{cyc}
3	D	External clock high time	t_{clkh}	1.5	—	t_{cyc}
4	D	External clock low time	t_{clkl}	1.5	—	t_{cyc}
5	D	Input capture pulse width	t_{ICPW}	1.5	—	t_{cyc}

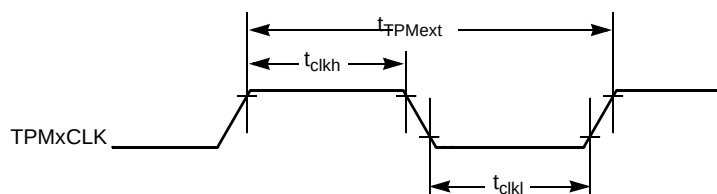


Figure 12. Timer External Clock

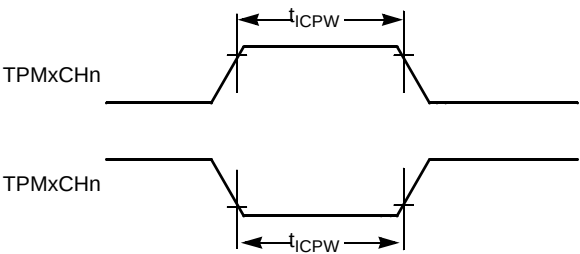


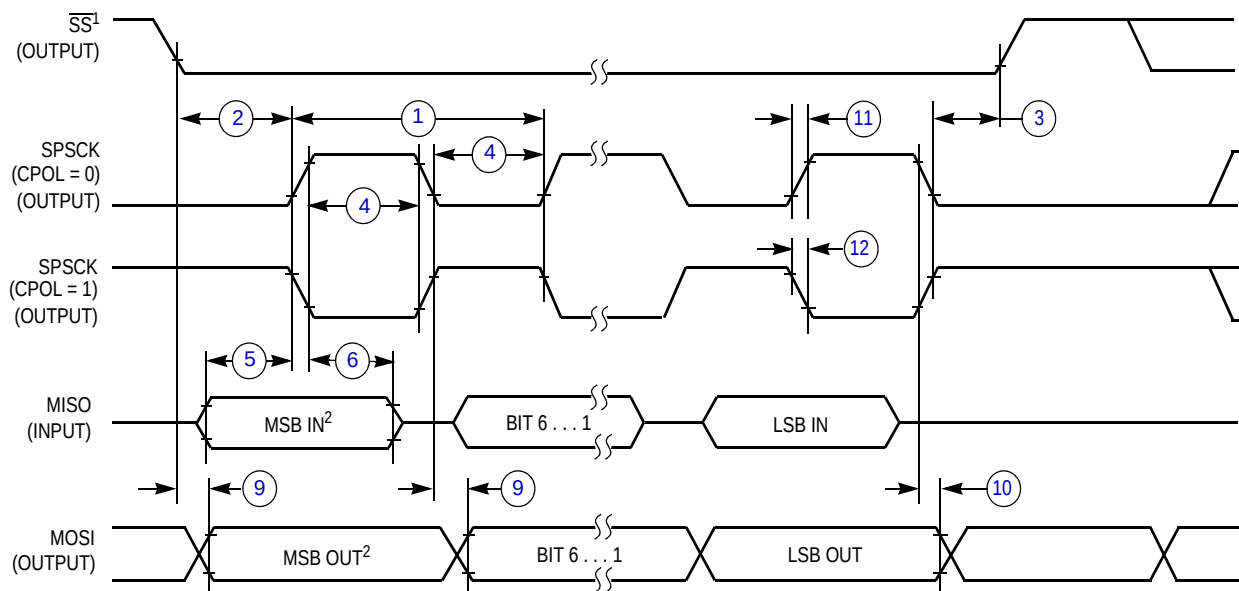
Figure 13. Timer Input Capture Pulse

2.11.3 MSCAN

Table 19. MSCAN Wake-up Pulse Characteristics

Num	C	Parameter	Symbol	Min	Typ ¹	Max	Unit
1	D	MSCAN Wake-up dominant pulse filtered	t_{WUP}			2	μs
2	D	MSCAN Wake-up dominant pulse pass	t_{WUP}	5		5	μs

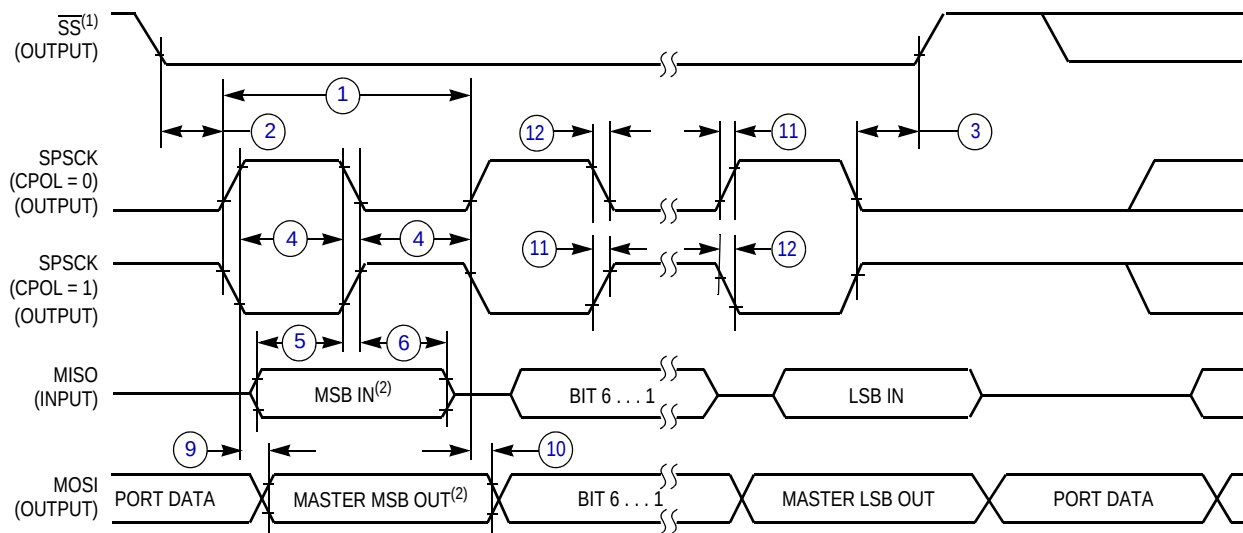
¹ Typical values are based on characterization data at $V_{DD} = 5.0\text{V}$, 25°C unless otherwise stated.



NOTES:

1. $\overline{SS}$ output mode (DDS7 = 1, SSOE = 1).
2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

Figure 14. SPI Master Timing (CPHA = 0)



NOTES:

1. $\overline{SS}$ output mode (DDS7 = 1, SSOE = 1).
2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

Figure 15. SPI Master Timing (CPHA = 1)

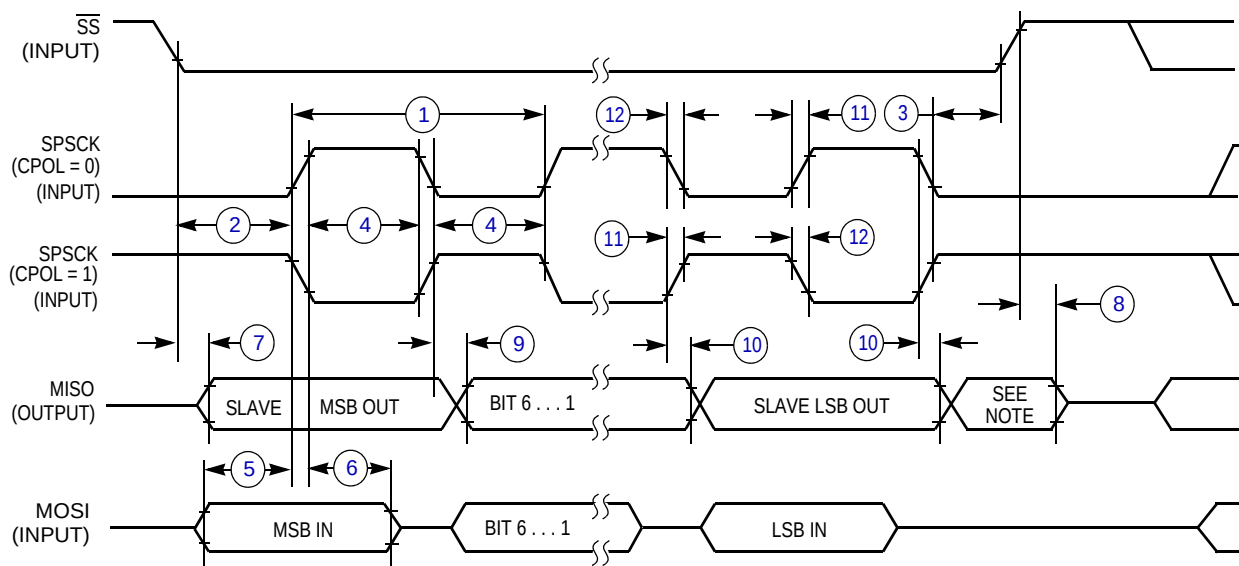


Figure 16. SPI Slave Timing (CPHA = 0)

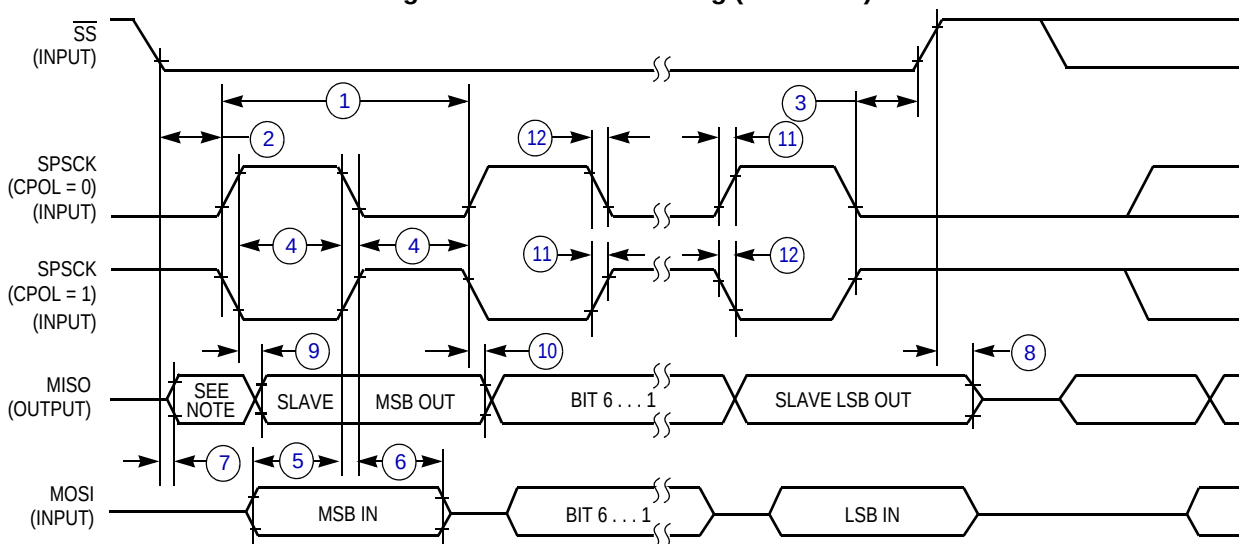


Figure 17. SPI Slave Timing (CPHA = 1)

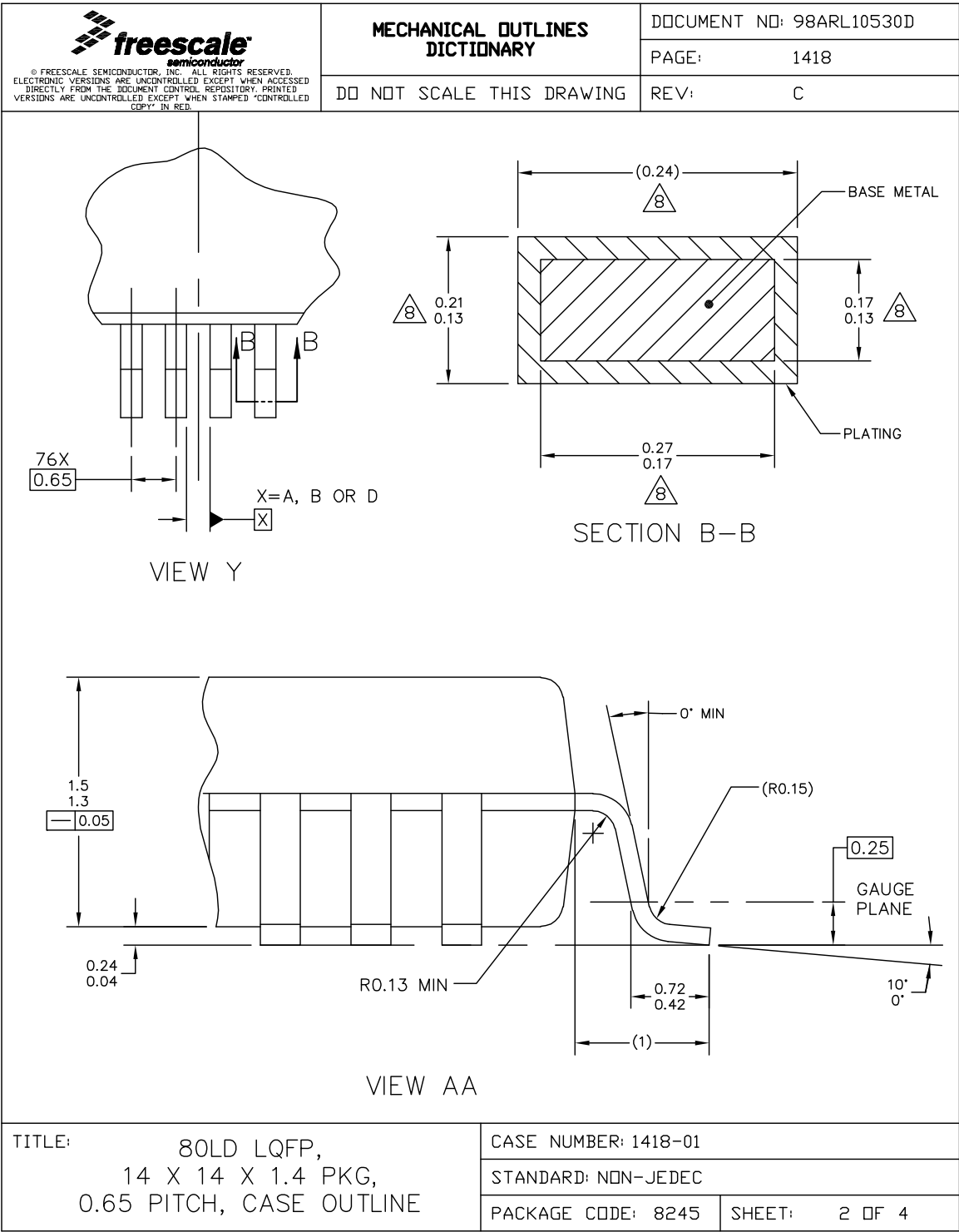


Figure 19. 80-pin LQFP Diagram - II

3.2 64-pin LQFP

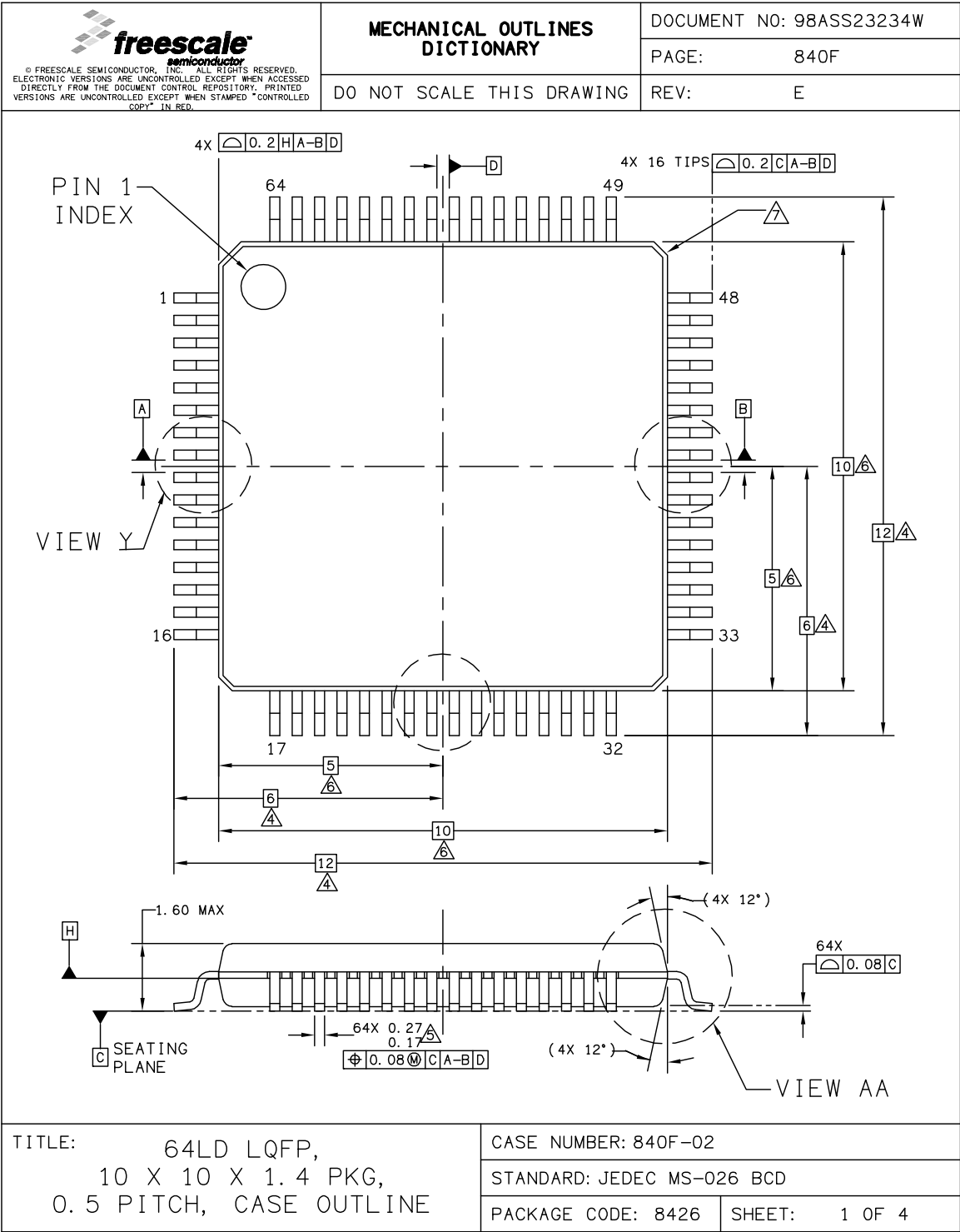


Figure 21. 64-pin LQFP Diagram - I

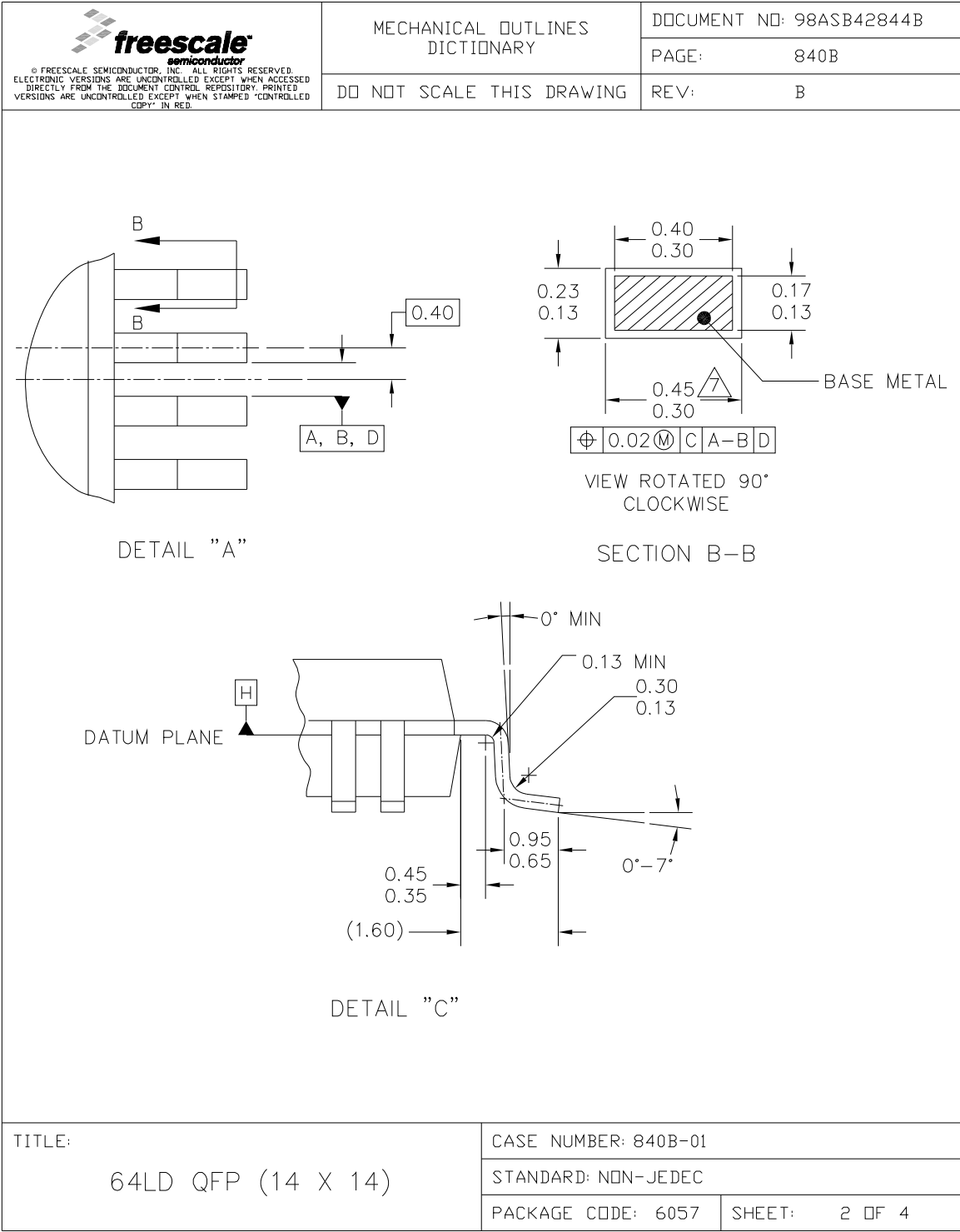


Figure 25. 64-pin QFP Diagram - II

3.4 44-pin LQFP

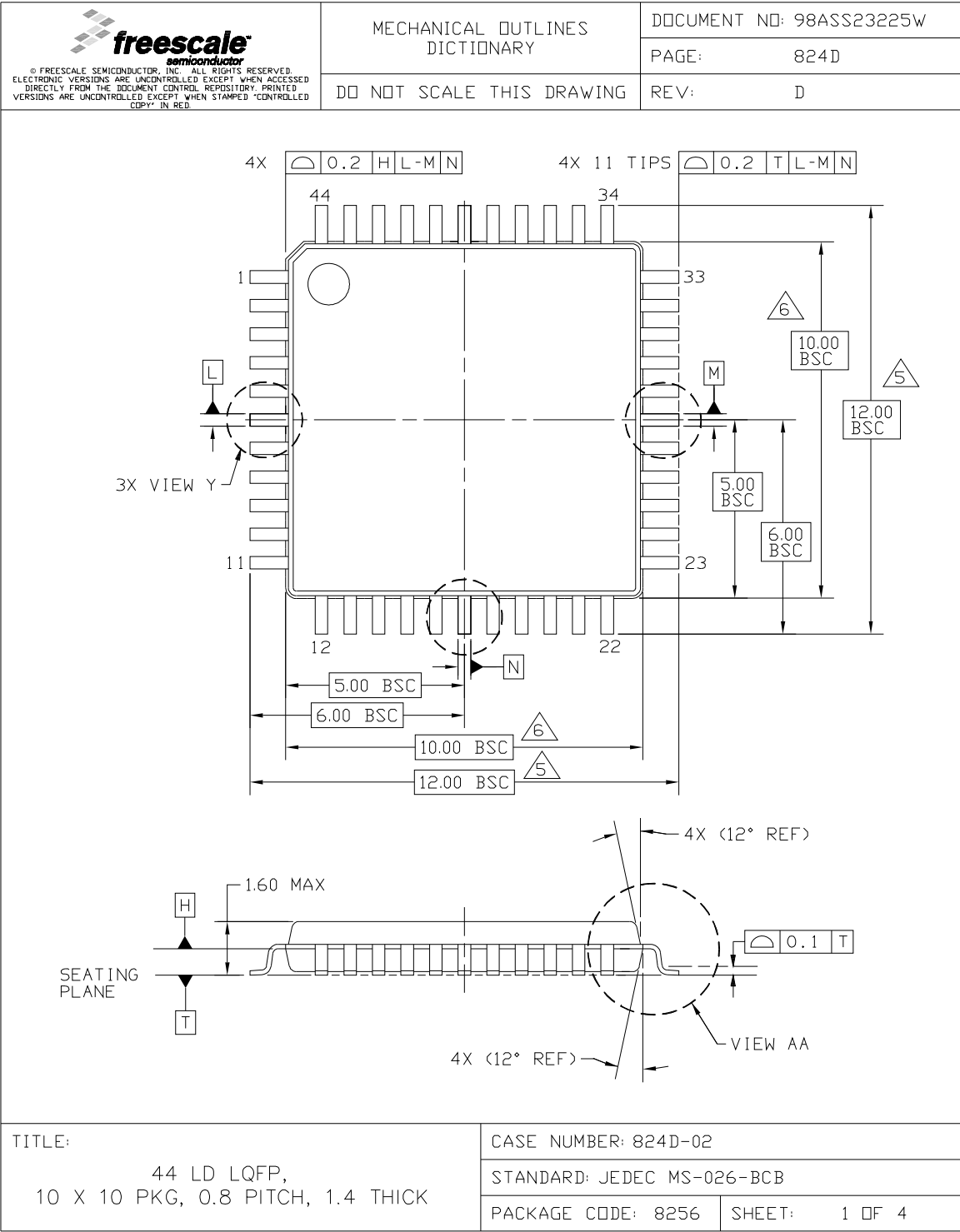


Figure 27. 44-pin LQFP Diagram - I

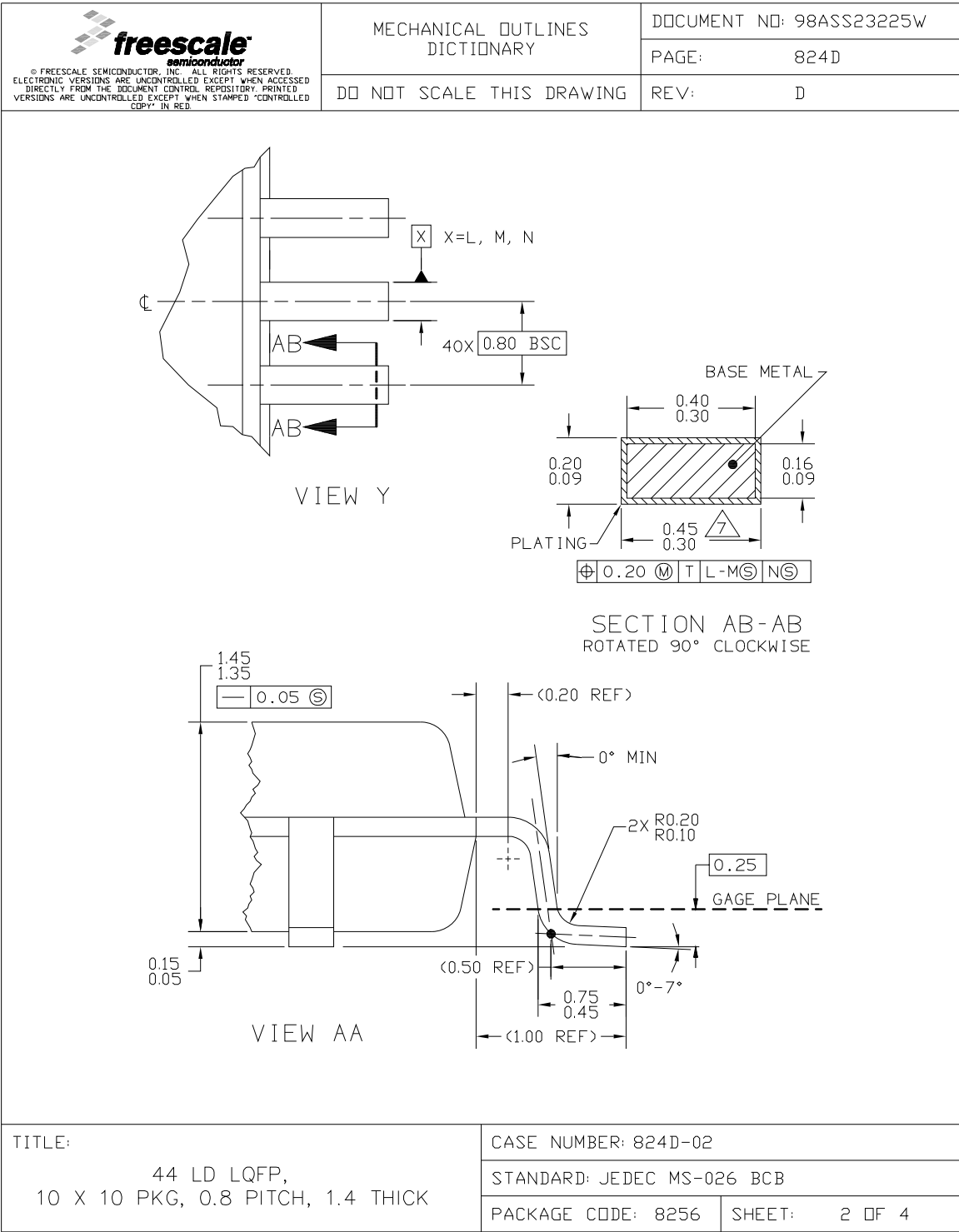


Figure 28. 44-pin LQFP Diagram - II

4 Revision History

This section lists major changes between versions of the MCF51JM128 Data Sheet document.

Table 23. Changes Between Revisions

Revision	Description
1	Updated features list Updated the figures Typical Low-side Drive (sink) characteristics – High Drive (PTxDSn = 1), Typical Low-side Drive (sink) characteristics – Low Drive (PTxDSn = 0), and Typical High-side Drive (source) characteristics – High Drive (PTxDSn = 1) Added the figure Typical High-side Drive (source) characteristics – Low Drive (PTxDSn = 0) Updated the table Supply Current Characteristics Updated the table Oscillator Electrical Specifications (Temperature Range = –40 to 105°C Ambient) Updated the table SPI Electrical Characteristic, DC Characteristics
2	Updated the table Orderable Part Number Summary, DC Characteristics, and Supply Current Characteristics
3	Updated the table Orderable Part Number Summary, MCG Characteristics, SPI Characteristics, and Supply Current Characteristics Changed V_{DDAD} to V_{DDA}, V_{SSAD} to V_{SSA} Updated the table Device comparison
4	Added “RAM retention voltage” parameter in “DC Characteristics” table, alongwith a table note. Added “Temp sensor voltage” parameter in “5 Volt 12-bit ADC Characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$)” table. Added “Temp sensor slope” parameter in 5 Volt 12-bit ADC Characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$) table. Also, corrected unit of “Temp sensor voltage” parameter in 5 Volt 12-bit ADC Characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$) table.